L Number	Hits	Search Text	DB	Time stamp
-	13615	interconnect\$4 and metallization	USPAT	2002/07/23 15:57
-	12026	(interconnect\$4 and metallization) and (trench opening via hole groove)	USPAT	2002/07/23 15:57
-	11649	((interconnect\$4 and metallization) and (trench opening via hole groove)) and (metal adj3 (layer film) conducting conductive contact)	USPAT	2002/07/23 15:58
-	11649	((interconnect\$4 and metallization) and (trench opening via hole groove)) and ((metal adj3 (layer film)) conducting conductive contact)	USPAT	2002/07/23 15:57
-	16522	interconnect\$4 and metallization	USPAT; US-PGPUB;	2002/07/23 15:57
			EPO; JPO; DERWENT; IBM_TDB	
-	13907	(interconnect\$4 and metallization) and (trench opening via hole groove)	USPAT; US-PGPUB;	2002/07/23 15:58
			EPO; JPO; DERWENT; IBM_TDB	
-	13267	((interconnect\$4 and metallization) and (trench opening via hole groove)) and (metal adj3 (layer film) conducting conductive contact)	USPAT; US-PGPUB;	2002/07/23 15:59
			EPO; JPO; DERWENT; IBM_TDB	
-	6482	(((interconnect\$4 and metallization) and (trench opening via hole groove)) and (metal adj3 (layer film) conducting conductive contact)) and	USPAT; US-PGPUB;	2002/07/23 16:01
		('FOX' 'LOCOS' isolat\$3)	EPO; JPO; DERWENT; IBM_TDB	
-	872	((((interconnect\$4 and metallization) and (trench opening via hole groove)) and (metal adj3 (layer film) conducting conductive contact)) and ('FOX' 'LOCOS' isolat\$3)) and (titanium adj3 (layer film))	USPAT; US-PGPUB; EPO; JPO;	2002/07/23 16:02
	00:		DERWENT; IBM_TDB	2002/07/22 14 22
-	834	(((((interconnect\$4 and metallization) and (trench opening via hole groove)) and (metal adj3 (layer film) conducting conductive contact)) and ('FOX' 'LOCOS' isolat\$3)) and (titanium adj3 (layer film))) and (dielectric insulat\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT;	2002/07/23 16:03
-	389	(((((((interconnect\$4 and metallization) and (trench opening via hole groove)) and (metal adj3 (layer film) conducting conductive contact)) and	IBM_TDB USPAT; US-PGPUB;	2002/07/23 16:03
		('FOX' 'LOCOS' isolat\$3)) and (titanium adj3 (layer film))) and (dielectric insulat\$3)) and voltage	EPO; JPO; DERWENT; IBM TDB	
•	389	'((((((((interconnect\$4 and metallization) and (trench opening via hole groove)) and (metal adj3 (layer film) conducting conductive contact)) and	USPAT; US-PGPUB;	2002/07/23 16:09
		('FOX' 'LOCOS' isolat\$3)) and (titanium adj3 (layer film))) and (dielectric insulat\$3)) and voltage) and (first second)	EPO; JPO; DERWENT; IBM_TDB	
-	17	((((((((((((((((((((((((((((((((((((((USPAT; US-PGPUB; EPO; JPO;	2002/07/23 16:05
		(dielectric insulat\$3)) and voltage) and (first second)) and metal adj trace	DERWENT; IBM_TDB	0000/07/02 4445
	120	((((((((interconnect\$4 and metallization) and (trench opening via hole groove)) and (metal adj3 (layer film) conducting conductive contact)) and ('FOX' 'LOCOS' isolat\$3)) and (titanium adj3 (layer film))) and	USPAT; US-PGPUB; EPO; JPO;	2002/07/23 16:10
		(dielectric insulat\$3)) and voltage) and (first second)) and plug	DERWENT; IBM_TDB	
-	1		USPAT	2002/07/23 18:02
-	1		USPAT	2002/07/23 18:02

